

L Number	Hits	Search Text	DB	Time stamp
1	4	313/\$.ccls. and organic and encapsulat\$ and moisture and williams.xa.	USPAT	2003/05/29 07:47
2	82	313/\$.ccls. and organic and encapsulat\$ and moisture	USPAT	2003/05/29 07:48
3	11	313/\$.ccls. and organic and encapsulat\$ and moisture and anode and cathode and laminat\$	USPAT	2003/05/29 08:32
4	37	313/\$.ccls. and organic and encapsulat\$ and moisture and anode and cathode	USPAT	2003/05/29 08:37
5	1	("5952778").PN.	USPAT	2003/05/29 08:40
6	20	("4356429" "4539507" "4983310" "5124204" "5169547" "5189549" "5214306" "5247190" "5296724" "5328580" "5337374" "5362410" "5373175" "5391756" "5408109" "5449926" "5593788" "5757126" "5771562" "5811177").PN.	USPAT	2003/05/29 08:37
7	11	5952778.URPN.	USPAT	2003/05/29 08:38
8	6	("5036249" "5124204" "5189405" "5771562" "5811177" "5952778").PN.	USPAT	2003/05/29 08:39
9	8	6198217.URPN.	USPAT	2003/05/29 08:39
10	1065	313/504	USPAT	2003/05/29 08:40
11	1437	((313/504) or (313/506) or (313/512)).CCLS.	USPAT	2003/05/29 09:06
12	5	("5124204" "6111357" "6210815" "6268071" "6284342").PN.	USPAT	2003/05/29 08:45
13	3	("4769292" "5122711" "5792557").PN.	USPAT	2003/05/29 08:51
14	1	("5952778").PN.	USPAT	2003/05/29 09:29
15	11	5952778.URPN.	USPAT	2003/05/29 09:06
16	0	6570325.pn. and cathode and anode	USPAT	2003/05/29 09:30
17	1	6570325.pn. and electrode	USPAT	2003/05/29 09:45
18	141	(passivation adj (film or layer)) and 313/\$.ccls.	USPAT	2003/05/29 09:46
19	24	(passivation adj (film or layer) same (Al or aluminum)) and 313/\$.ccls.	USPAT	2003/05/29 09:52
20	84	(passivation adj (film or layer) same (Au or gold or indium or In)) and 313/\$.ccls.	USPAT	2003/05/29 09:57
21	19	(passivation adj (film or layer) same (Au or gold or indium)) and 313/\$.ccls.	USPAT	2003/05/29 09:59
22	6	(passivation adj (film or layer) same (Au of gold)) and 313/\$.ccls.	USPAT	2003/05/29 10:01
23	957	(passivation adj (film or layer) same (Au of gold))	USPAT	2003/05/29 10:16

24	957	(passivation adj (film or layer) same (Au or gold))	USPAT	2003/05/29 12:01
25	161	silicon same nitride same plasma same CVD same silane same nitrogen	USPAT	2003/05/29 12:13
26	1	(silicon same nitride same plasma same CVD same silane same nitrogen) and electroluminescence	USPAT	2003/05/29 12:03
27	0	(silicon same nitride same plasma same CVD same silane same nitrogen) and 445/\$.ccls.	USPAT	2003/05/29 12:06
28	498	(shadow adj mask) and 445/\$.ccls.	USPAT	2003/05/29 12:07
30	36	williams.xa. and day.xp. and cathode and 313/\$.ccls.	USPAT	2003/05/29 12:20
31	120	williams.xa. and patel.xp. and cathode and 313/\$.ccls.	USPAT	2003/05/29 12:20
32	32	williams.xa. and patel.xp. and cathode and 313/\$.ccls. and grid	USPAT	2003/05/29 12:26
33	697	313/407	USPAT	2003/05/29 12:26
34	432	(313/407).CCLS.	USPAT	2003/05/29 12:28
35	89	(313/407).CCLS.	US-PGPUB	2003/05/29 12:26
36	0	313/407.ccis. and (busbar same glass same rigid)	USPAT	2003/05/29 12:29
37	3	313/407.ccis. and (busbar same glass)	USPAT	2003/05/29 12:30
38	0	313/407.ccis. and (busbar same glass)	USOCR	2003/05/29 12:30
39	0	(shadow adj mask) and (busbar same glass)	EPO; JPO; DERWENT; IBM_TDB	2003/05/29 12:31
40	71	busbar same glass	USOCR	2003/05/29 12:31
41	0	(busbar same glass) and mask and CRT	USOCR	2003/05/29 12:31
42	6	(busbar same glass) and mask	USOCR	2003/05/29 12:33
43	432	(313/407).CCLS.	USPAT	2003/05/29 12:35
44	1	("6175185").PN.	USPAT	2003/05/29 12:38
45	0	(shadow adj mask) and (hole same bulge)	USPAT	2003/05/29 12:42
46	0	(shadow adj mask) and (bulge)	USPAT	2003/05/29 12:42
47	2	("5635320" "5856725").PN.	USPAT	2003/05/29 12:39
48	53	(shadow adj mask) and (bulge)	USPAT	2003/05/29 12:42
49	7	(shadow adj mask) and (hole same bulge)	USPAT	2003/05/29 12:43
50	2	(shadow adj mask) and (slot same bulge)	USPAT	2003/05/29 12:43

29	102	silicon same nitride same (plasma adj CVD) same silane same nitrogen	USPAT	2003/05/29 12:45
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